

TECHNICAL DATA DATA SHEET 400, REV. -

Ultra Fast T_{rr} < 12 nsec ULTRA LOW REVERSE LEAKAGE POWER SCHOTTKY RECTIFIER Very Low Forward Voltage Drop

Applications:

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

Features:

- Ultra Low Reverse Leakage Current
- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics
- Electrically / Mechanically Stable during and after Packaging
- Out Performs 200 Volt Ultra fast Rectifiers

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	200	V
Max. Average Forward Current	I _{F(AV)}	50% duty cycle @T _C =100 ℃, rectangular wave form	15	А
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	140	A
Non-Repetitive Avalanche Energy (per leg)	E _{AS}	$T_J = 25 ^{\circ}\text{C}, \ I_{AS} = 0.4 \text{A}, \\ L = 40 \text{mH}$	7.7	mJ
Repetitive Avalanche Current (per leg)	I _{AR}	I_{AS} decay linearly to 0 in 1 μ s f limited by T_J max V_A =1.5 V_R	0.4	А
Max. Junction Temperature	T_J	-	-65 to +200	°C
Max. Storage Temperature	T _{stg}	-	-65 to +175	°C

Electrical Characteristics:

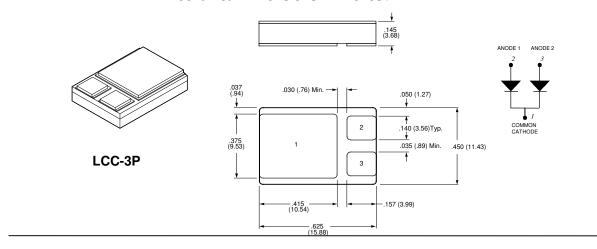
Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 15A, Pulse, T _J = 25 °C	1.0	V
(per leg)	V_{F2}	@ 15A, Pulse, T _J = 125 °C	0.84	V
Max. Reverse Current	I _{R1}	@V _R = 200V, Pulse,	0.008	mA
(per leg)		T _J = 25 °C		
	I _{R2}	$@V_R = 200V$, Pulse,	0.5	mA
		T _J = 125 °C		
Max. Junction Capacitance	C_{T}	$@V_R = 5V, T_C = 25 ^{\circ}C$	150	pF
(per leg)		$f_{SIG} = 1MHz,$		
		$V_{SIG} = 50 \text{mV (p-p)}$		
Maximum Thermal Resis.	$R_{ hetaJC}$	-	3.0	°C/W
(per leg)				
Max. Reverse Recovery	t _{rr}	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{RM} = 0.25 \text{ A}, T_J = 25 ^{\circ}\text{C}$	12	nsec
Time (per leg)		$I_{RM} = 0.25 \text{ A}, T_{J} = 25 ^{\circ}\text{C}$		

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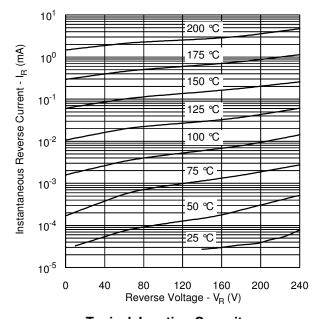
Mechanical Dimensions: In Inches / mm



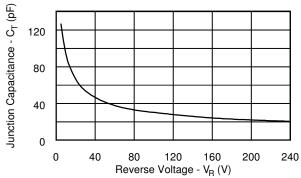
Typical Forward Characteristics

10¹ 200 ℃ 175 ℃ 10⁰ Instantaneous Forward Current - I_F (A) 10⁻¹ 125 ℃ 25 ℃ 10⁻² 10⁻³ 0.0 0.2 0.4 0.6 8.0 1.0 Forward Voltage Drop - V_F (V)

Typical Reverse Characteristics









TECHNICAL DATA

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